



Electrical Engineering
National Taiwan University

電子學一

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Course Outline

- Microelectronic Circuits
 - Part 1: Devices and Basic Circuits (Chapter 1~6)**
 1. Signals, Amplifiers, and Semiconductors
 2. Operational Amplifiers
 3. Diodes
 4. Bipolar Junction Transistors (BJTs)
 5. MOS Field-Effect Transistors (MOSFETs)
 6. Transistor Amplifiers
 - Part 2: Analog Integrated Circuits (Chapter 7~13)**
 7. Building Blocks of Integrated Circuit Amplifiers
- Handwriting on blackboard for later lectures.



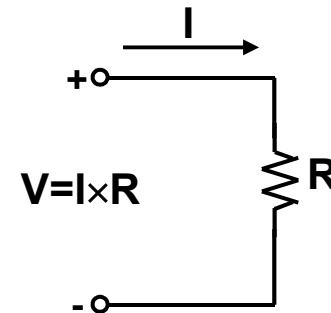
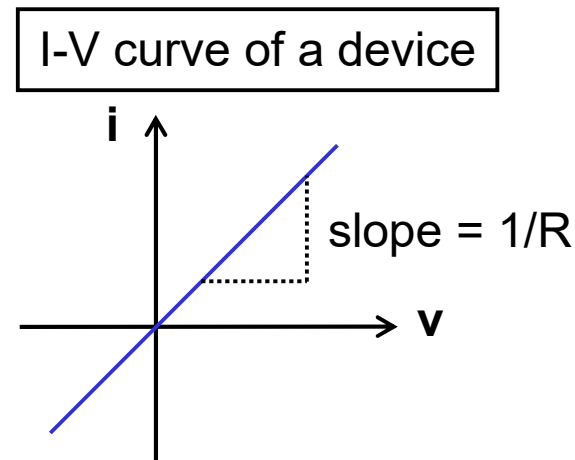
Week 1: Introduction

- Review
- Chapter1: Signals, Amplifiers, and Semiconductors
 - learn basic concepts and terminology
 - Signals
 - Frequency spectrum of signals
 - Analog and digital signals
 - Amplifiers
 - Circuit models for amplifiers
 - Frequency response of amplifiers
 - 1.7 ~ 1.12 (Semiconductor, pn junction); move to later part



Basic Device - Resistor

- For a linear resistor:
 - $V = I \times R$ (Ohm's Law)
 - R : resistance, unit: ohm (Ω)
- Conductance (G)
 - $G = 1/R$, unit: mho, siemen (Ω^{-1} , S)
- Power dissipation:
 - $P = V \times I = I^2 \times R = V^2/R$
 - Power consumed by a resistor is dissipated in the form of heat (ohmic heating)
 - e.g. toaster, fuse





Resistivity

- Resistivity (ρ) is a material property



$$R = \rho \frac{L}{A}$$

Rubber (insulator)	$\rho = 10^{12}$
Silicon (semiconductor)	$\rho = 2300$
Copper (conductor)	$\rho = 1.7 \times 10^{-8}$
Aluminum (conductor)	$\rho = 2.8 \times 10^{-8}$

- Sheet resistance (R_{\square})

$$R = \rho \frac{L}{WH} = \frac{\rho}{H} \frac{L}{W} = R_{\square} \times (\text{number of squares}); \quad R_{\square} = \frac{\rho}{H}$$



- Sheet resistance and resistivity are important parameters in integrated circuit (IC) designs.
- Resistance varied with temperature (temperature dependent)



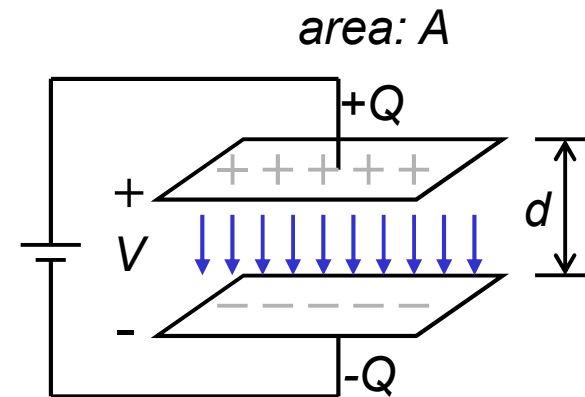
Capacitor

- Passive elements: R, C, L
 - R: dissipate energy
 - C and L: store energy
- A capacitor consists of 2 conducting plates separated by an insulator (dielectric).
- For a linear capacitor:

$$C = \frac{Q}{V}$$

$$i = \frac{dQ}{dt} = \frac{d(CV)}{dt} = C \frac{dV}{dt}$$

$$v(t) = \frac{1}{C} \int_{t_0}^t i dt + v(t_0)$$



$$C = \epsilon \frac{A}{d}$$

$$\epsilon = \epsilon_0 \epsilon_r$$

ϵ_0 : free space permittivity
 $8.854 \times 10^{-12} \text{ F/m}$

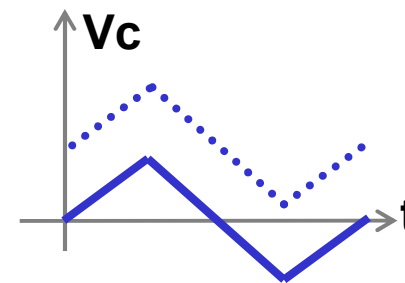
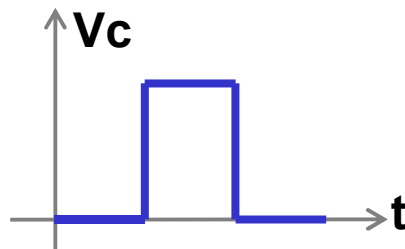
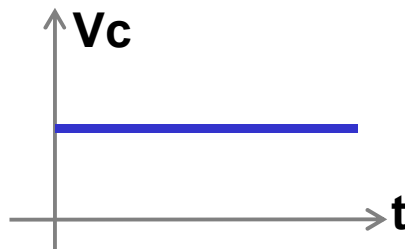
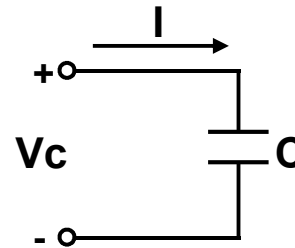
ϵ_r : relative permittivity
(dielectric constant)



Capacitor

- Three cases:

$$i = C \frac{dV}{dt}$$



- A capacitor is an open circuit at DC.
- The voltage on a capacitor must be continuous.

-
- Power delivered to a capacitor:

$$P = vi = vC \frac{dv}{dt} \Rightarrow Pdt = Cvdv \Rightarrow W = \int Pdt = \int Cvdv$$

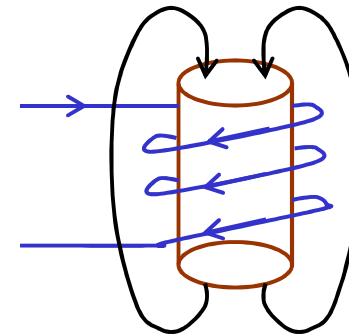
$$W = \frac{1}{2} C v^2 = \frac{1}{2} \frac{Q^2}{C} \quad (\text{the energy stored in a capacitor})$$



Inductor

- Capacitors store energy in an electric field, while inductors store energy in a magnetic field.
- Magnetic field is induced by passing current through a coil of wire.
- Faraday's Law: time-varying current induces a voltage in the coil

$$v = L \frac{di}{dt} \quad (i = C \frac{dv}{dt})$$



- An inductor is a short circuit at DC.
- The current through an inductor must be continuous.

-
- Power delivered to an inductor:

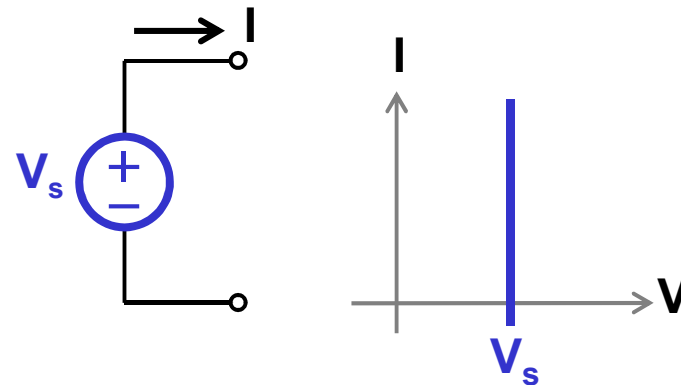
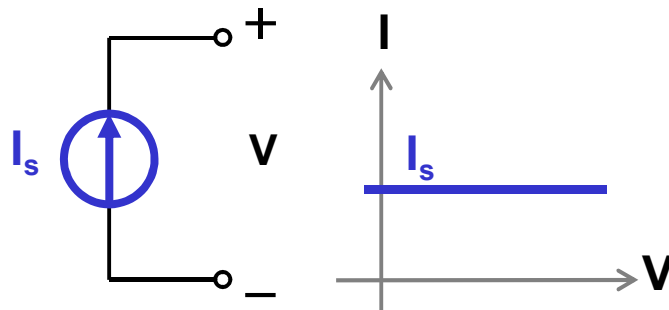
$$P = vi = L \frac{di}{dt} i \Rightarrow P dt = L i di \Rightarrow W = \int P dt = \int L i di$$

$$W = \frac{1}{2} L i^2 \quad (\text{the energy stored in an inductor})$$

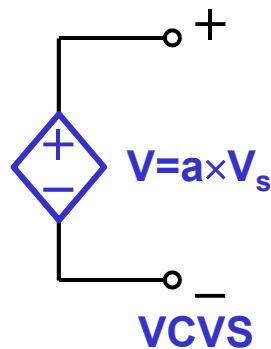


Sources

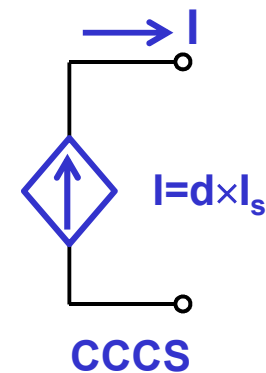
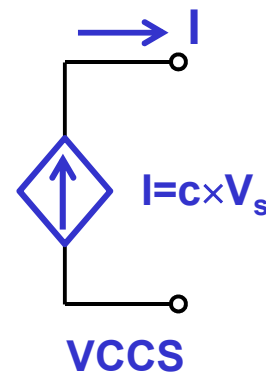
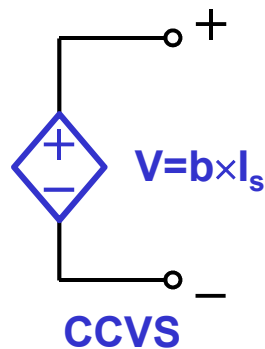
- Independent (ideal) sources



- Dependent (controlled) sources



(voltage-controlled voltage source)

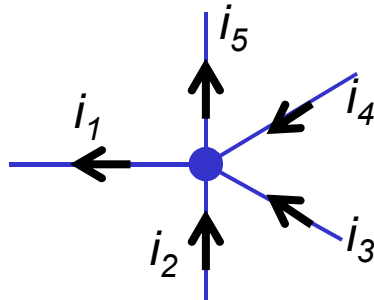


(current-controlled current source)



KCL & KVL

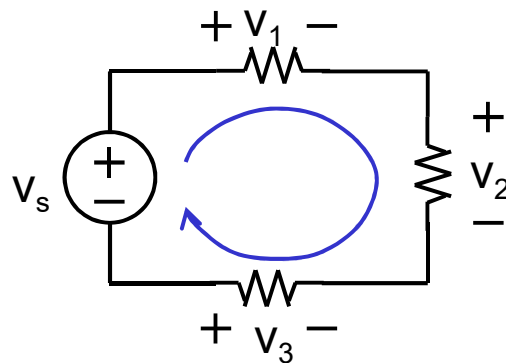
- Kirchhoff's Current Law (KCL): the sum of all currents at a circuit node is zero.



$$(-i_1) + i_2 + i_3 + i_4 + (-i_5) = 0$$

$$\sum(i_n) = 0$$

- Kirchhoff's Voltage Law (KVL): the sum of all voltages around a closed path (loop) is zero.



$$v_s + (-v_1) + (-v_2) + v_3 = 0$$

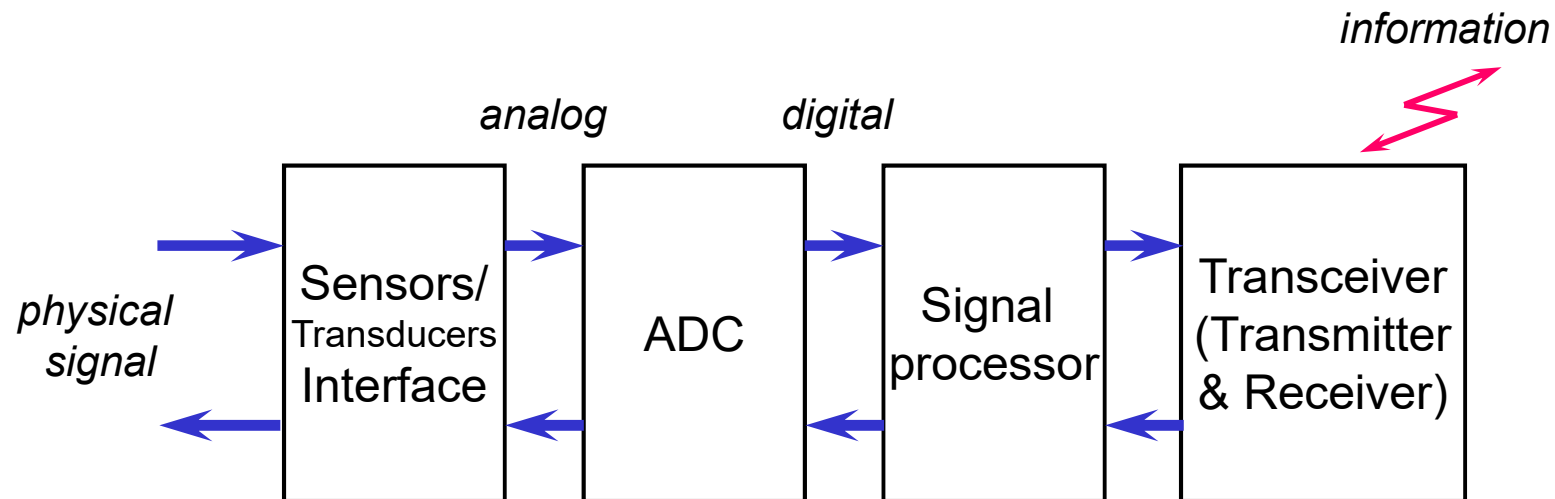
$$\sum(v_n) = 0$$

- Conservation of energy!



An Electronic System

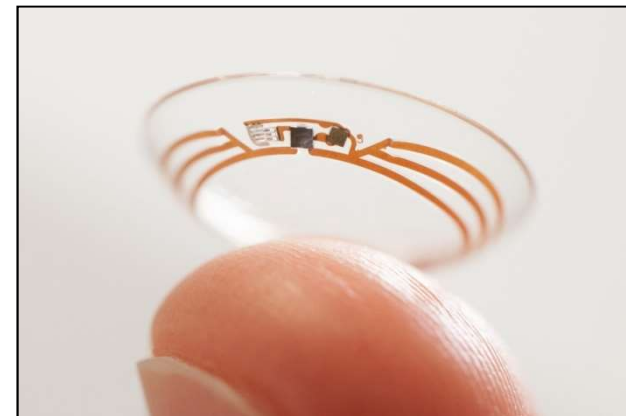
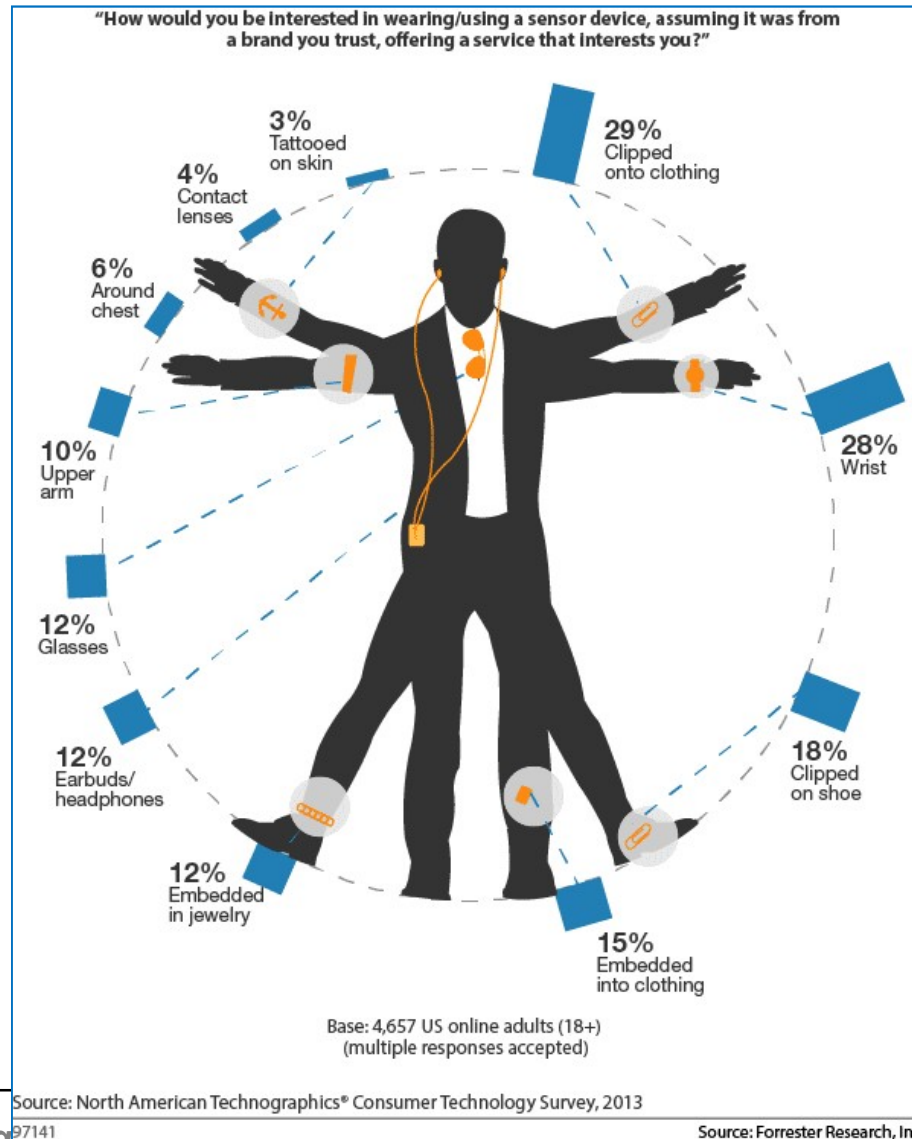
- A generic electronic system (e.g. an **IoT** device, or a **wearable** device)



- Electronics and microelectronics
 - From vacuum tubes to discrete transistors, to integrated circuits



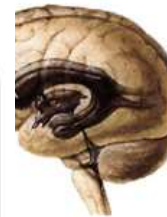
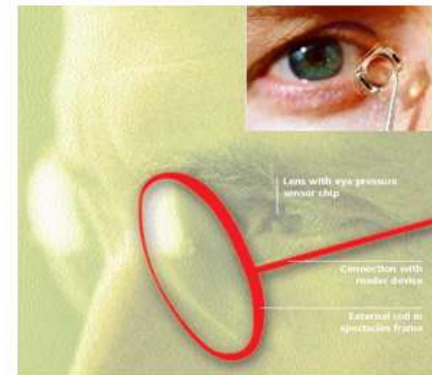
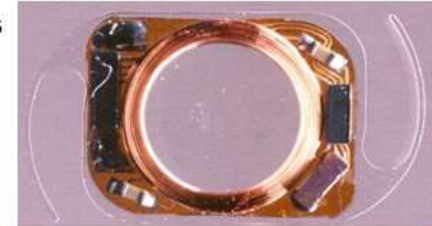
Wearable Devices





Implanted Device

- Glaucoma is one of the common causes for blindness.
- Losing peripheral vision and developing tunnel vision.
- Caused by increased pressure in the eyeball, which impairs the blood supply to the retina.
- Require continuous monitoring of the eye pressure.
- Implanted pressure sensor



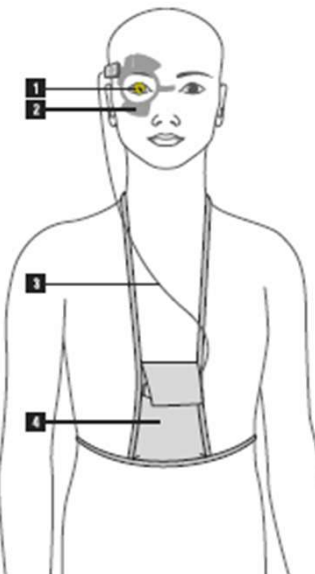
Glaucoma Contact Lens

- Wireless MEMS Sensor-Embedded Contact Lens for Glaucoma Treatment



- A two-part system that incorporates a receiver worn by the patient around his neck and the smart contact lens. Besides the strain gauge the lens incorporates an RF transmitter, a miniature processing circuit, and an antenna for conveying measured data to the receiver.

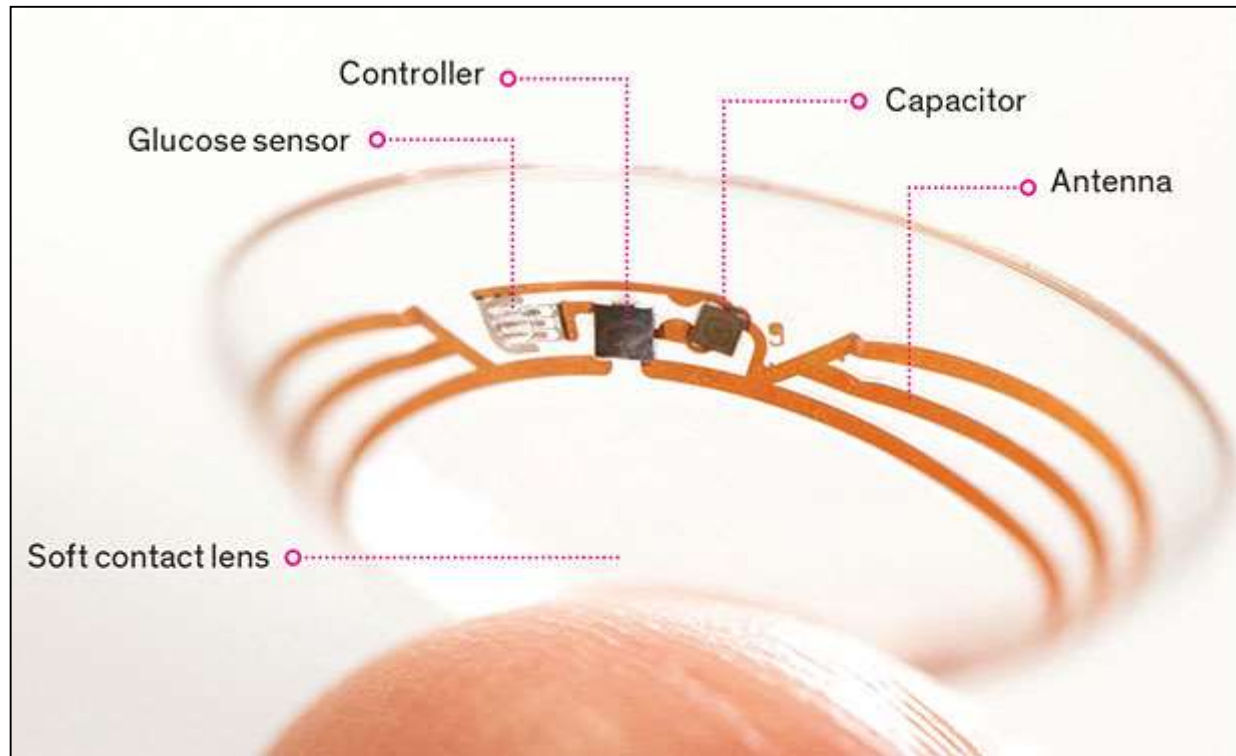
(Sensimed's Triggerfish Lens)





Wearable – Contact Lens

- IEEE Spectrum, July 2017



(Verily Life Sciences)

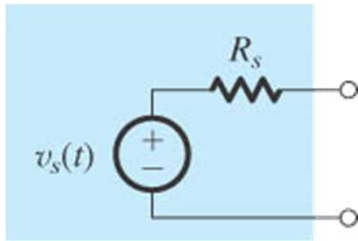


The Greatest Wearable Device

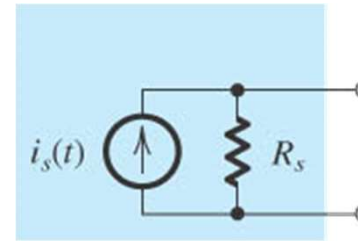


Signals

- Physical signal vs. electrical signal
 - Transducers convert physical signals into electrical signals
- Electrical signals:
 - Voltage signal
 - Current signal



Thévenin equivalent circuit



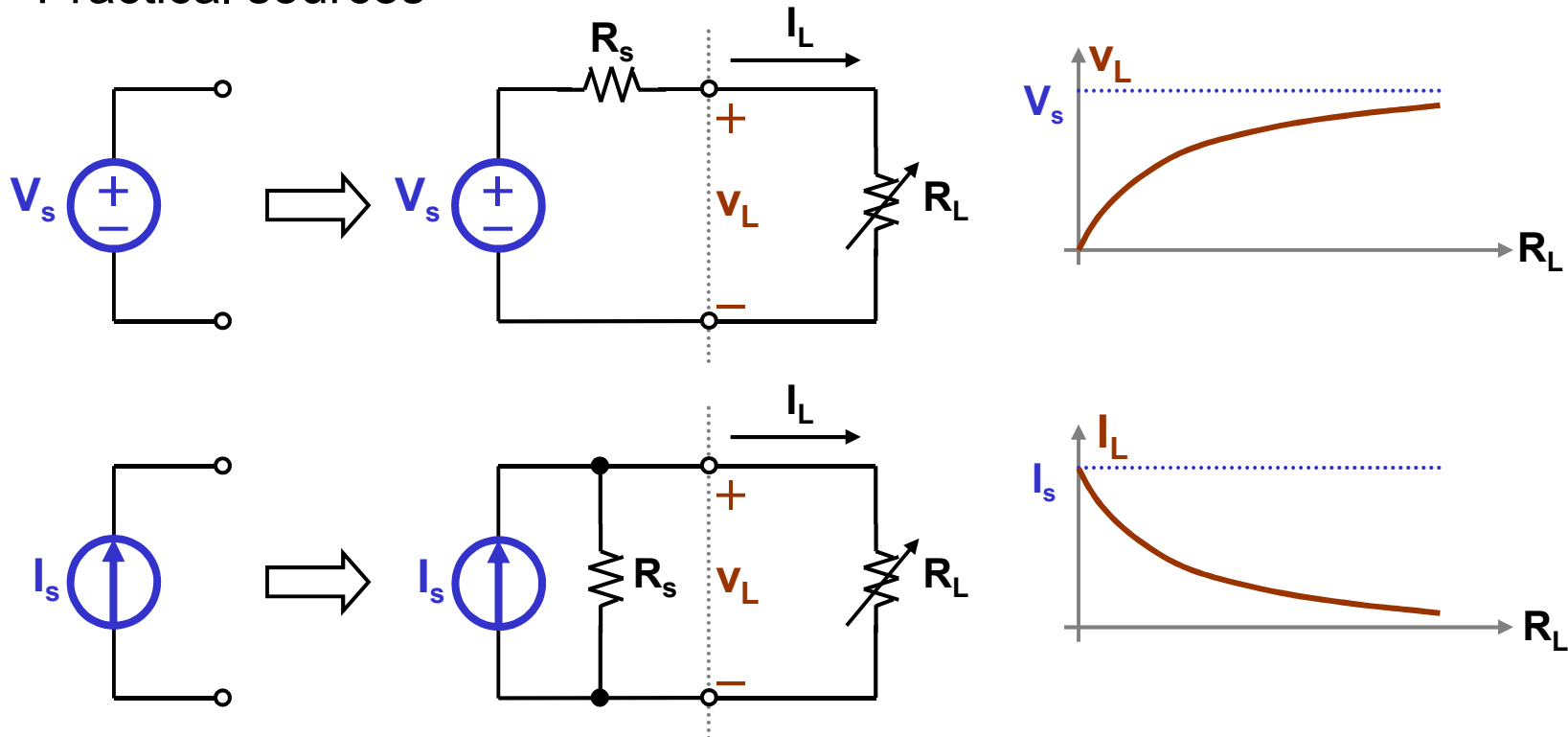
Norton equivalent circuit

- For an ideal voltage/current source, $R_s = ?$
- What is the role of R_s ?



Signal Source Modeling

- Practical sources



- Considering the load R_L , how to maximize the output voltage (V_L) or current (I_L)?

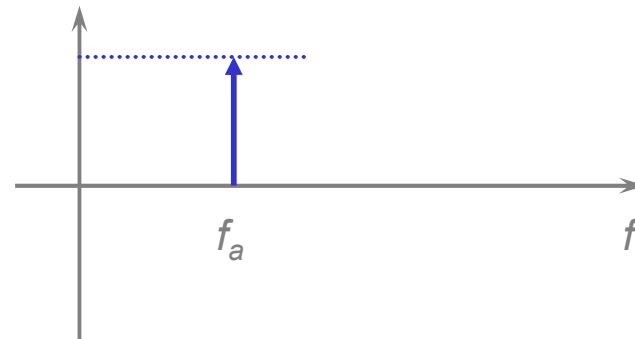
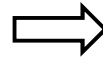
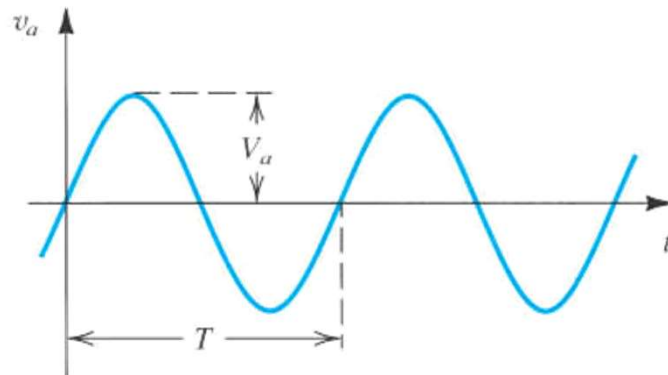


Signals

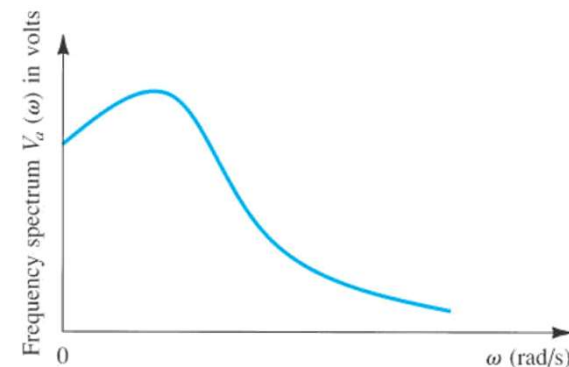
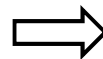
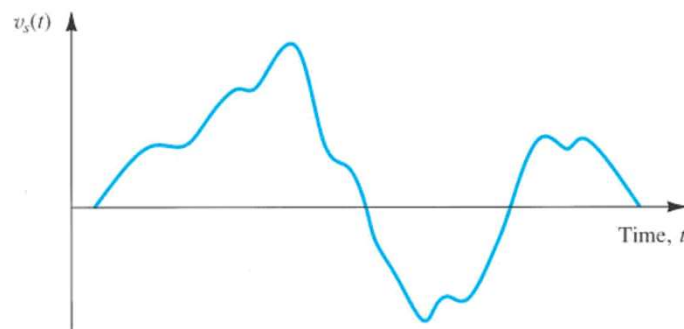
- Time domain vs. Frequency domain

– $V(t) = V_a \times \sin(\omega t) = V_a \times \sin(2\pi f_a t)$

$\Rightarrow \omega = 2\pi f_a; f_a = 1/T$



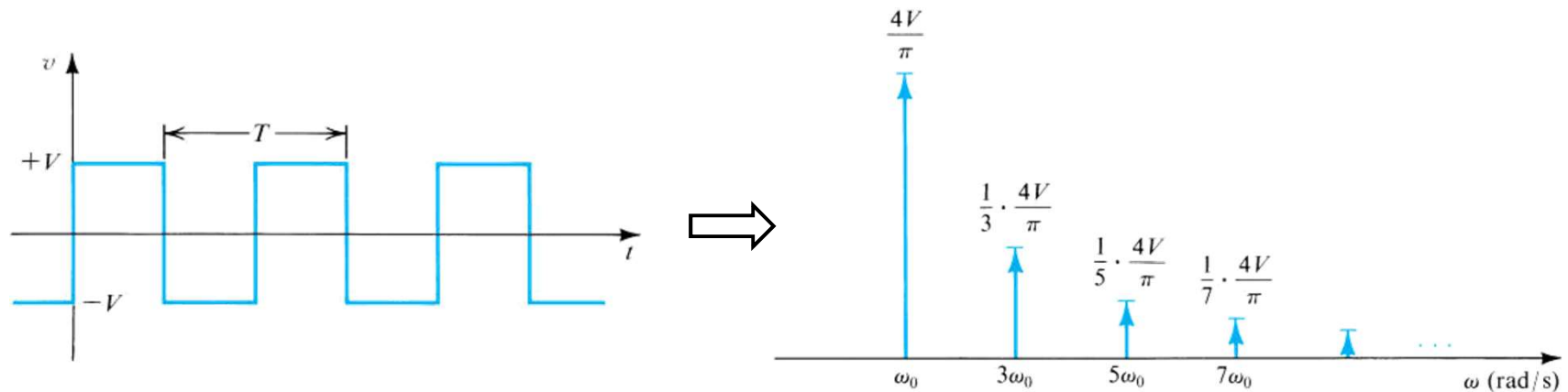
- For a “random” signal





Signals

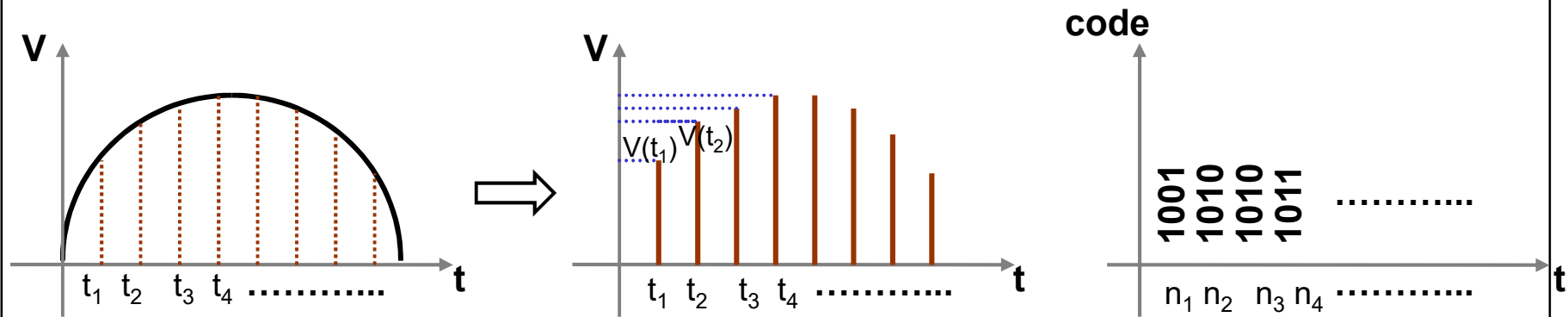
- Conversion from time domain to frequency domain
 - Fourier transform and Fourier series (will be covered in “Signal and System”)
 - For a square wave $\Rightarrow v(t) = \frac{4V}{\pi} (\sin \omega_0 t + \frac{1}{3} \sin 3\omega_0 t + \frac{1}{5} \sin 5\omega_0 t + \dots)$





Analog and Digital Signals

- Analog signals: continuous
- Digital signals: signal represented by a sequence of numbers



Continuous-time analog signal $\xrightarrow{\text{sample}}$ Discrete-time analog signal $\xrightarrow{\text{quantize}}$ Digital signal





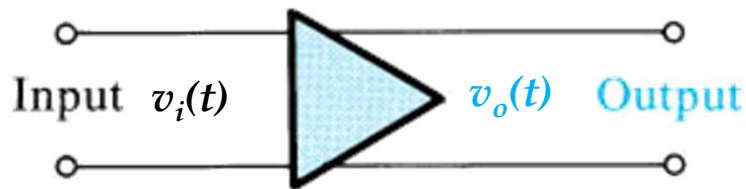
Amplifiers

- Amplification

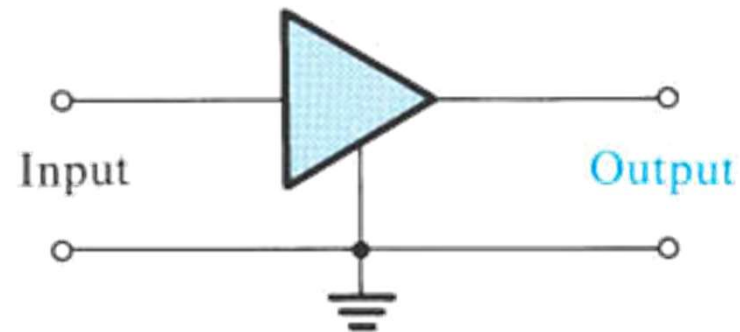
$$v_o(t) = Av_i(t) + Bv_i(t)^2 + Cv_i(t)^3 + \dots$$

- Linear amplification: $B=C= \dots =0$ (Linear Properties)
- Non-linear amplification \Rightarrow distortion

- Symbol:



(a)

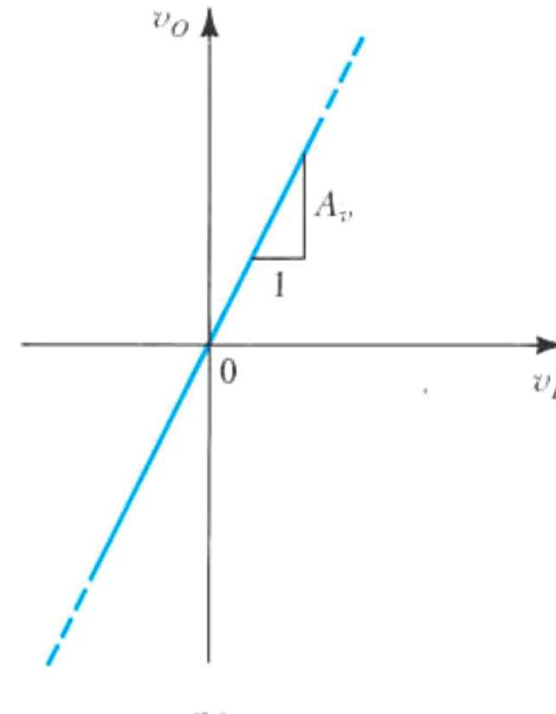
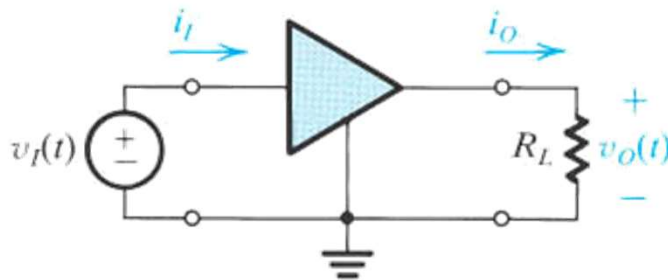


(b)



Gain

- Voltage, current, and power gains

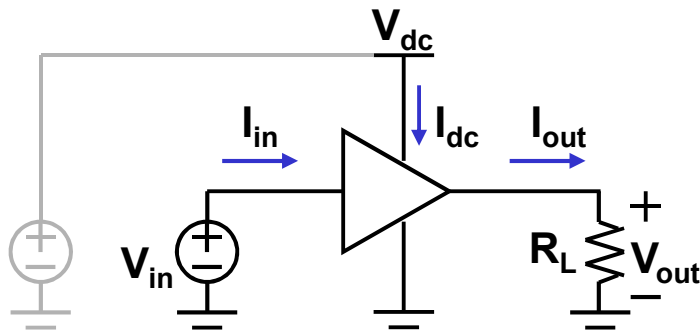


- Voltage gain (A_v) $= v_o/v_i$ (V/V)
- Current gain (A_i) $= i_o/i_i$ (I/I)
- Power gain (A_p) $= v_o i_o / v_i i_i$ (W/W)
- Decibels (dB)
 - $20 \times \log |A_v|$
 - $20 \times \log |A_i|$
 - $10 \times \log |A_p|$



Power Dissipation

- Power consumption



- Single power supply

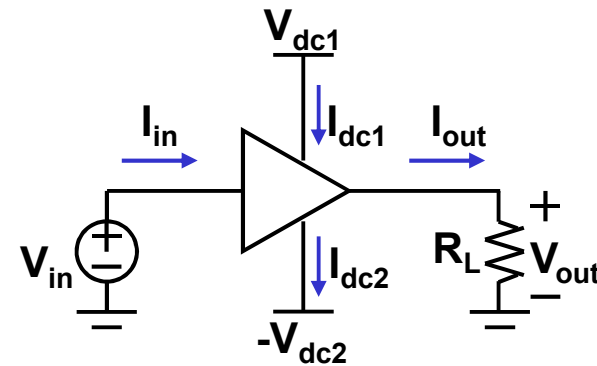
$$P_{dc} = V_{dc} \times I_{dc}$$

$$P_{in} = V_{in} \times I_{in}$$

$$P_L = V_{out} \times I_{out}$$

- Efficiency

$$\eta \equiv \frac{P_L}{P_{dc}} \times 100\%$$



- Dual power supply

$$P_{dc} = V_{dc1} \times I_{dc1} + (-V_{dc2}) \times (-I_{dc2})$$

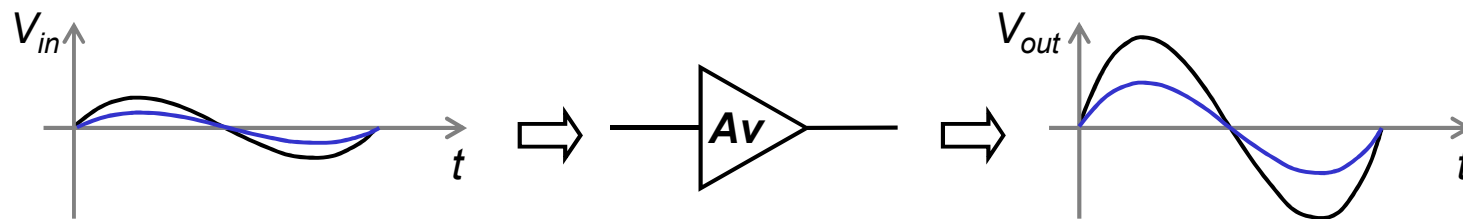
$$P_{in} = V_{in} \times I_{in}$$

$$P_L = V_{out} \times I_{out}$$

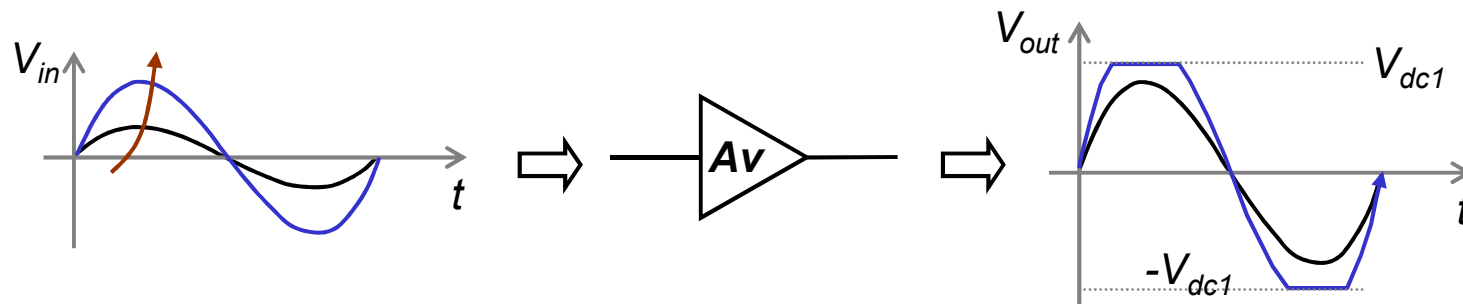


Amplifier Saturation

- Amplify signals (with information)



- What if input amplitudes keep increasing?
 - Output waveform is limited by DC power supply voltages

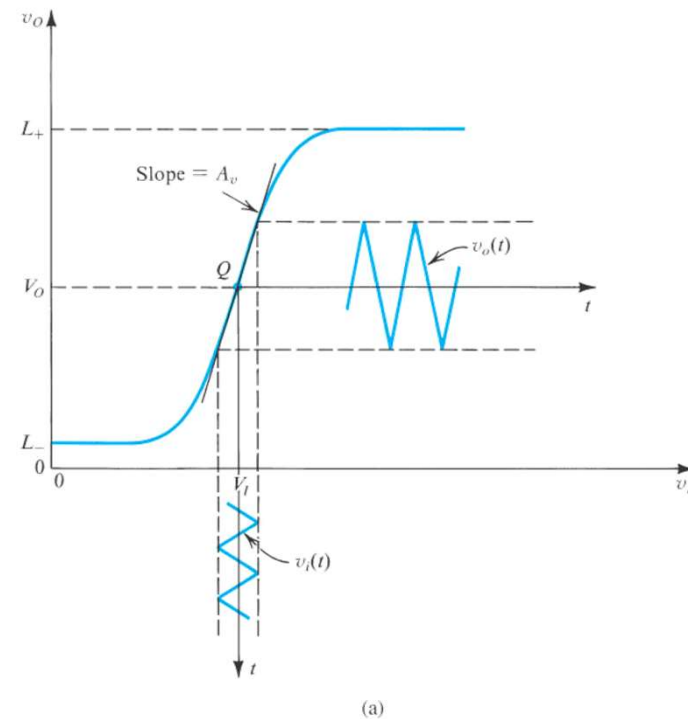
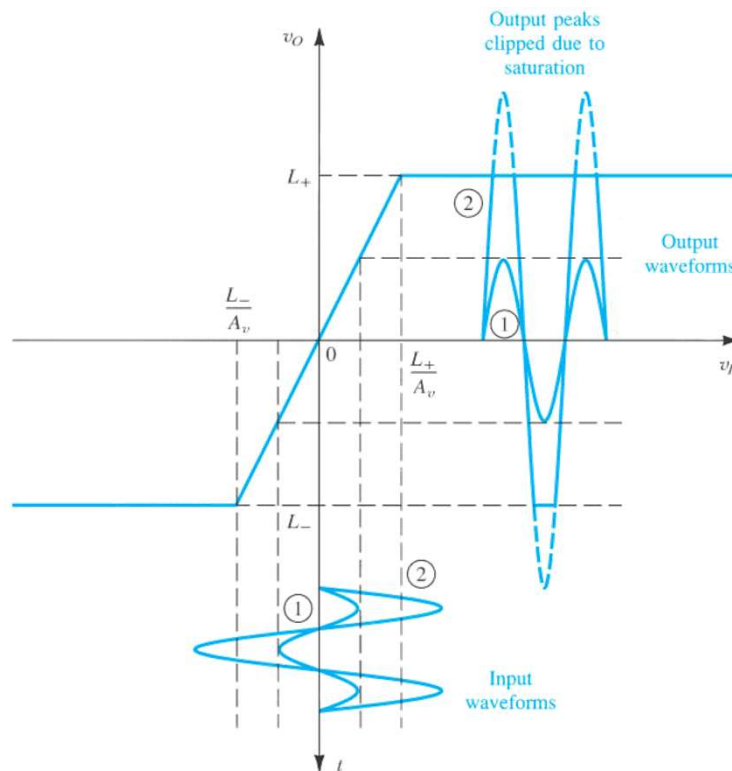


- Saturation (clipping)



Transfer Characteristics

- Transfer characteristic (transfer curve, v_i - v_o curve)
 - Ideal case
 - practical case

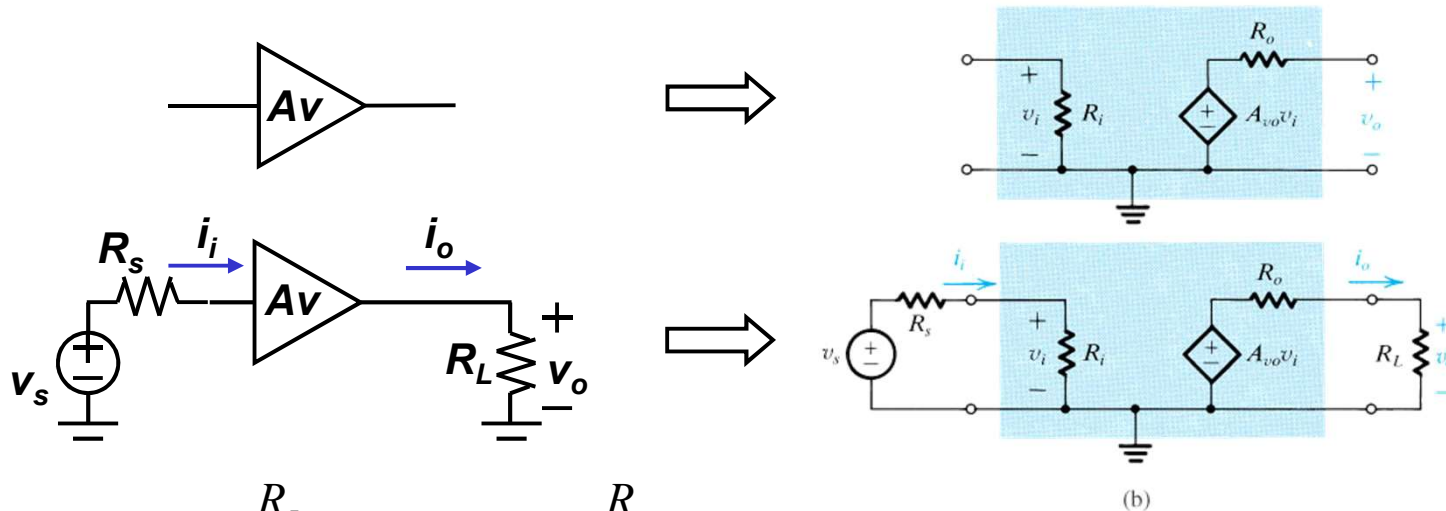


- Proper biasing and small-signal operation



Amplifier Model

- Model: represent a complex circuit with a simplified version
 - Can have many versions of models, depends on biasing
 - Simplify circuit analysis



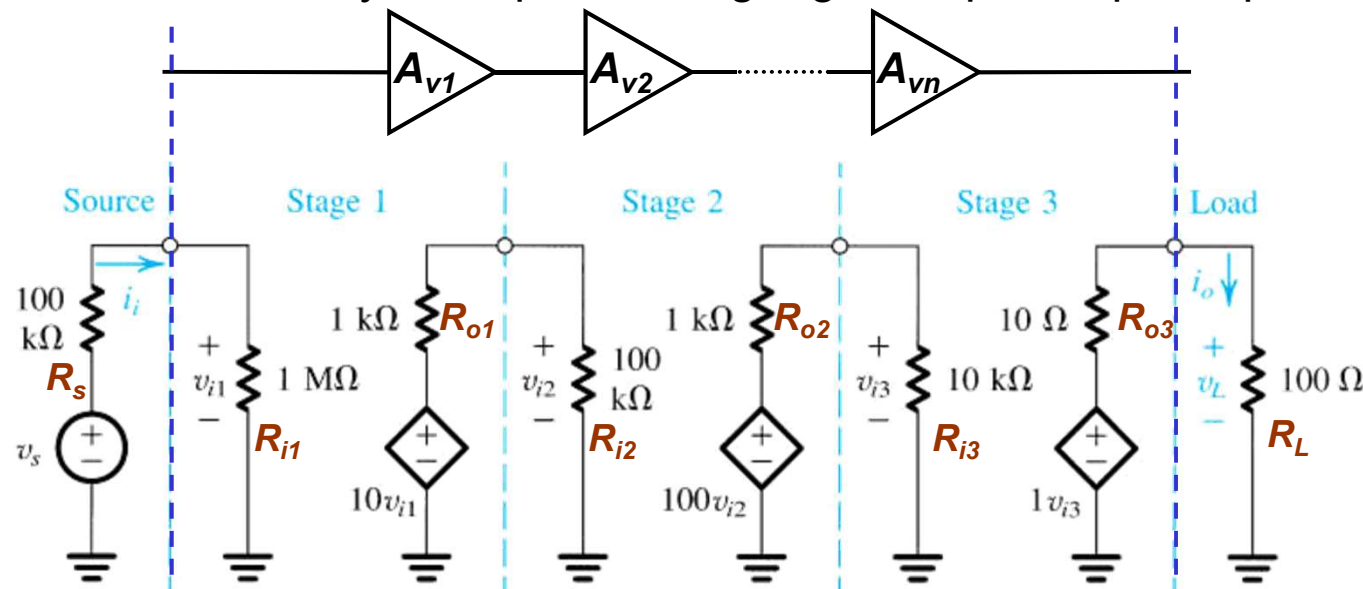
$$v_o = A_{v0} v_i \frac{R_L}{R_L + R_o}; \quad v_i = v_s \frac{R_i}{R_s + R_i}$$

$$v_o = A_{v0} v_s \frac{R_i}{R_s + R_i} \frac{R_L}{R_L + R_o} \Rightarrow \frac{v_o}{v_s} = A_{v0} \frac{R_i}{R_s + R_i} \frac{R_L}{R_L + R_o}$$



Cascaded Amplifier

- Allow more flexibility in amplifier design: gain, input/output impedance, etc.



$$v_L = A_{v3} v_{i3} \frac{R_L}{R_{o3} + R_L}; \quad v_{i3} = A_{v2} v_{i2} \frac{R_{i3}}{R_{o2} + R_{i3}}; \quad v_{i2} = A_{v1} v_{i1} \frac{R_{i2}}{R_{o1} + R_{i2}}; \quad v_{i1} = v_s \frac{R_{i1}}{R_s + R_{i1}}$$

$$v_o = v_s A_{v3} A_{v2} A_{v1} \frac{R_L}{R_{o3} + R_L} \frac{R_{i3}}{R_{o2} + R_{i3}} \frac{R_{i2}}{R_{o1} + R_{i2}} \frac{R_{i1}}{R_s + R_{i1}}$$



Four Amplifier Types

Type	Model	Gain Expression	Ideal Case
Voltage Amplifier		$A_{vo} \equiv \left. \frac{v_o}{v_i} \right _{i_o=0} \quad (V/V)$	$R_i = \infty, R_o = 0$
Current Amplifier		$A_{is} \equiv \left. \frac{i_o}{i_i} \right _{v_o=0} \quad (A/A)$	$R_i = 0, R_o = \infty$
Transconductance Amplifier		$G_m \equiv \left. \frac{i_o}{v_i} \right _{v_o=0} \quad (A/V)$	$R_i = \infty, R_o = \infty$
Transresistance Amplifier		$R_m \equiv \left. \frac{v_o}{i_i} \right _{i_o=0} \quad (V/A)$	$R_i = 0, R_o = 0$



Amplifier Type

- These four types are equivalent

$$\begin{aligned} A_{vo} &= \frac{v_o}{v_i} = \frac{i_o R_o}{i_i R_i} = A_{is} \left(\frac{R_o}{R_i} \right) \\ &= \frac{v_o}{i_i R_i} = \frac{R_m}{R_i} \\ &= \frac{i_o R_o}{v_i} = G_m R_o \end{aligned}$$

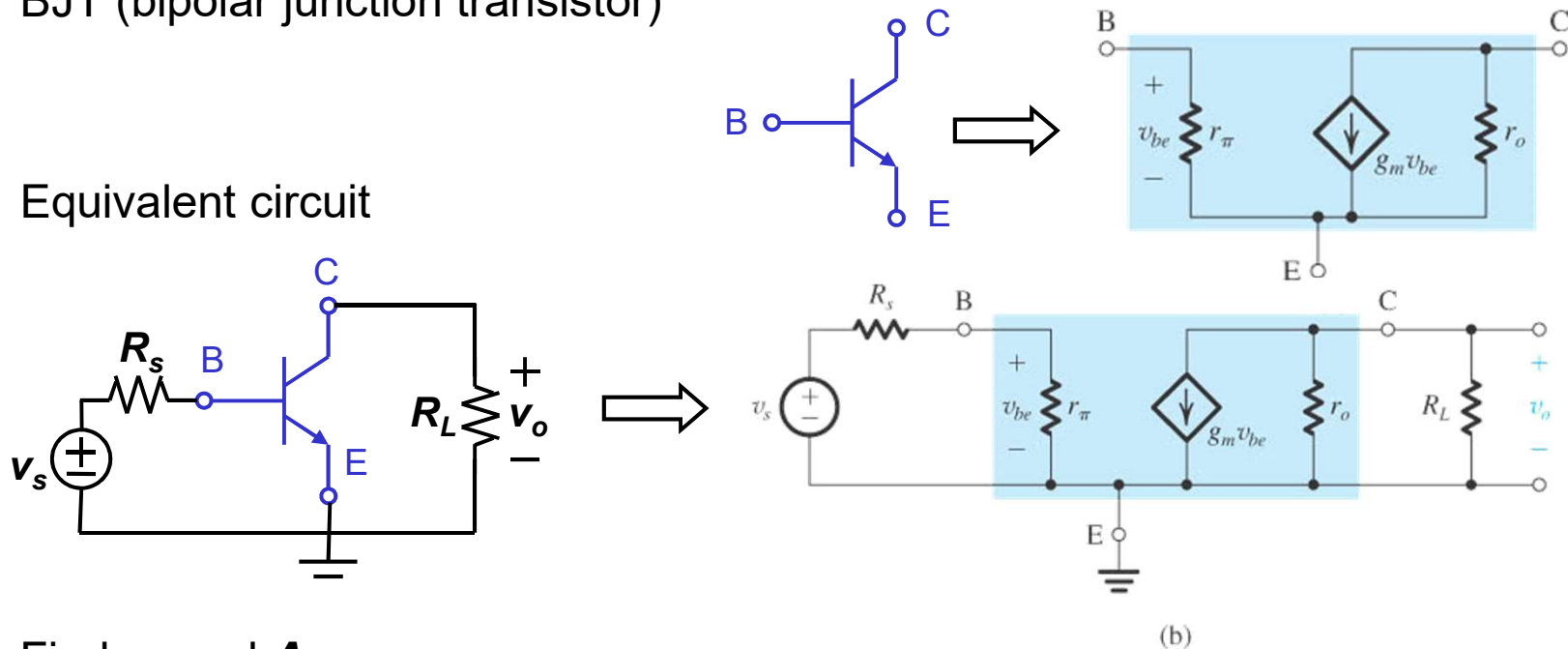
- These models are two-port networks
- These models are unilateral



Example 1.4

- BJT (bipolar junction transistor)

- Equivalent circuit



- Find v_o and A_v

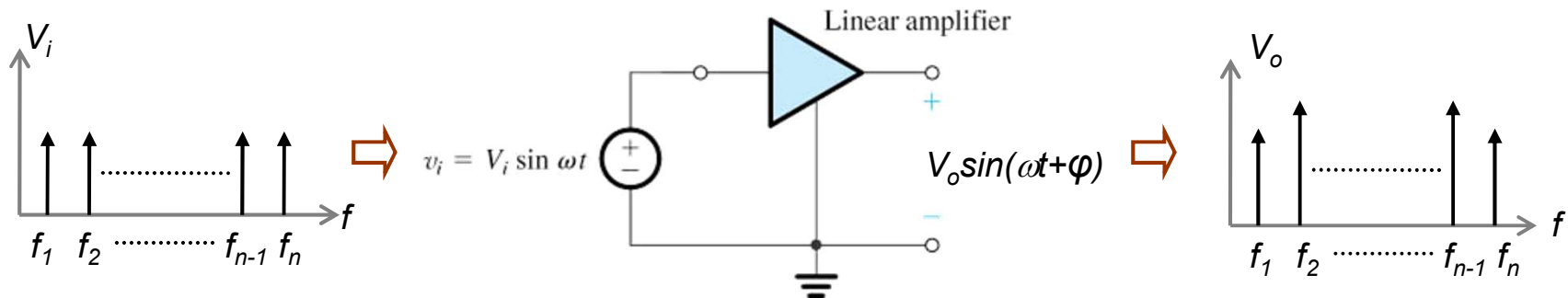
$$v_o = (-g_m v_{be})(R_L \parallel r_o)$$

$$v_{be} = v_s \frac{r_\pi}{R_s + r_\pi} \Rightarrow v_o = -g_m v_s \frac{r_\pi}{R_s + r_\pi} (R_L \parallel r_o) \Rightarrow A_v = \frac{v_o}{v_s} = -g_m \frac{r_\pi}{R_s + r_\pi} (R_L \parallel r_o)$$



Frequency Response

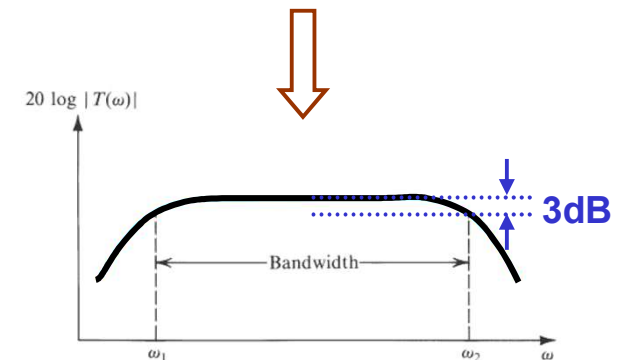
- Different amplifications at different frequencies



$$A_v = \frac{V_o}{V_i} \Rightarrow A_v(\omega) = \frac{V_o(\omega)}{V_i(\omega)} \quad (\text{Transfer function})$$

$$\angle A_v(\omega) = \phi$$

- Only frequency-dependent components cause frequency response
 - R, L, C: ???





Frequency Dependence of Devices

- Describing devices in time-domain can be quite complicated

$$i = C \frac{dv}{dt}; \quad \text{if } v = v_A \sin(\omega t) \Rightarrow i = C\omega v_A \cos(\omega t) \quad \text{For a certain } \mathbf{v} \text{ (amplitude } v_A), \mathbf{i} \text{ grows as } \omega \text{ increases.}$$
$$\Rightarrow \frac{v_A}{i} \propto \frac{1}{C\omega}$$

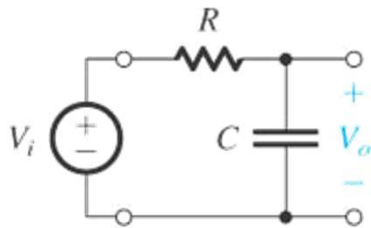
$$v = L \frac{di}{dt}; \quad \text{if } i = i_A \sin(\omega t) \Rightarrow v = L\omega i_A \cos(\omega t) \quad \text{For a certain } \mathbf{i} \text{ (amplitude } i_A), \mathbf{v} \text{ grows as } \omega \text{ increases.}$$
$$\Rightarrow \frac{v}{i_A} \propto L\omega$$

- Define “impedance” in the frequency domain
 - Why impedance? (recall basic circuit analysis techniques: KCL, KVL, and Ohm’s Law)
 - $Z_L = j\omega L = sL$ (reactance or impedance); $s = j\omega$
 - $Z_C = 1/j\omega C = 1/sC$ (reactance or impedance)
 - $Z_R = R$ (resistance or impedance)



STC Network

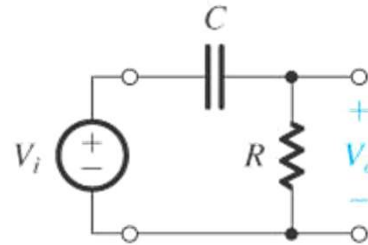
- A STC network: a RC or RL circuit
 - Time constant $\tau = RC$ or L/R
- **RC low pass (LP) network**



$$T(s) = \frac{v_o}{v_i} = \frac{1/sC}{R + 1/sC} = \frac{1}{1 + sRC} = \frac{1}{1 + s/\omega_0} \quad \omega_0 = 1/RC$$

$$T(\omega) = \frac{1}{1 + j\omega/\omega_0} \Rightarrow |T(\omega)| = \frac{1}{\sqrt{1 + (\omega/\omega_0)^2}}$$
$$\angle T(\omega) = -\tan^{-1}(\omega/\omega_0)$$

- **RC high pass (HP) network**



$$T(s) = \frac{v_o}{v_i} = \frac{R}{R + 1/sC} = \frac{sRC}{1 + sRC} = \frac{s}{\omega_0 + s} \quad \omega_0 = 1/RC$$

$$T(\omega) = \frac{j\omega}{\omega_0 + j\omega} \Rightarrow |T(\omega)| = \frac{1}{\sqrt{(\omega_0/\omega)^2 + 1}}$$
$$\angle T(\omega) = \tan^{-1}(\omega_0/\omega)$$

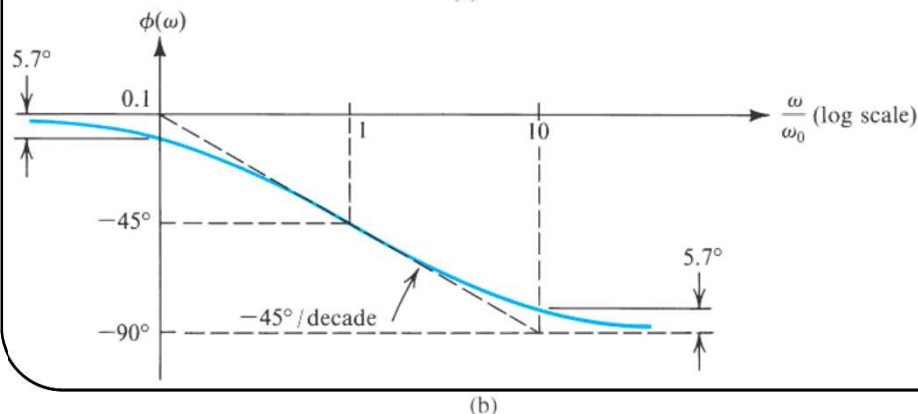
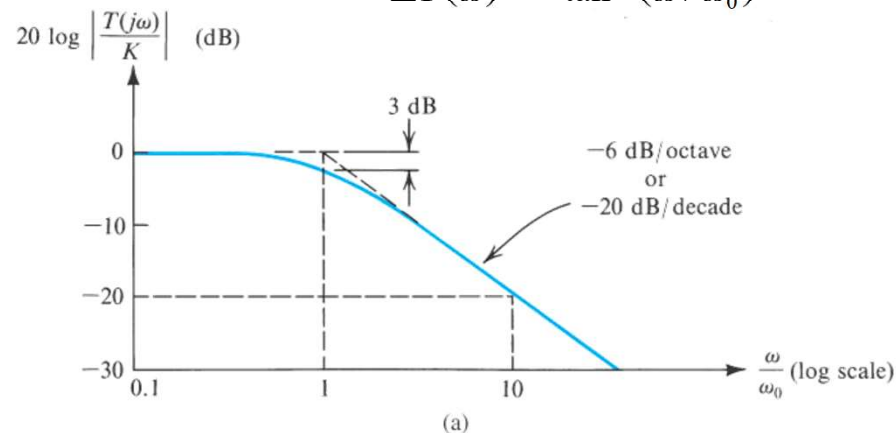


STC Circuit Bode Plots

- LPF**

$$T(\omega) = \frac{1}{1 + j\omega/\omega_0} \Rightarrow |T(\omega)| = \frac{1}{\sqrt{1 + (\omega/\omega_0)^2}}$$

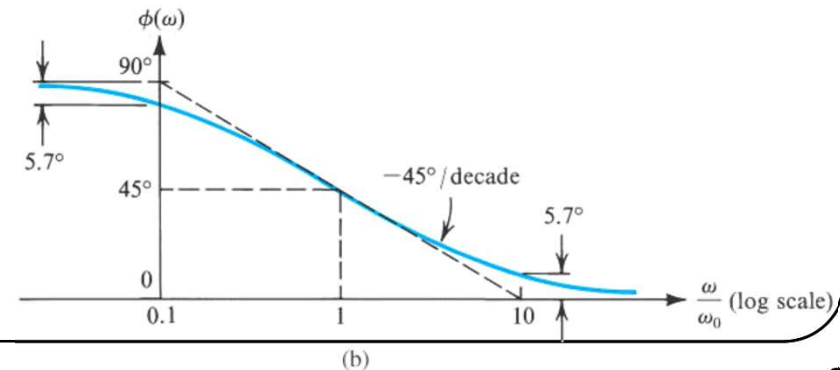
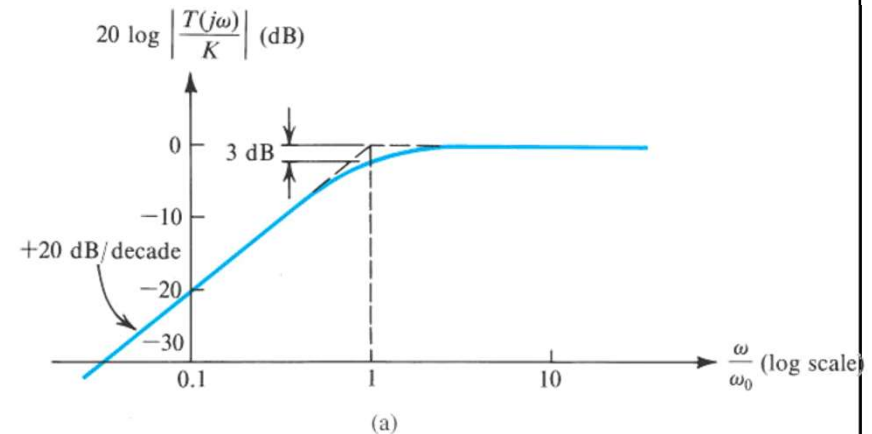
$$\angle T(\omega) = -\tan^{-1}(\omega/\omega_0)$$



- HPF**

$$T(\omega) = \frac{j\omega}{\omega_0 + j\omega} \Rightarrow |T(\omega)| = \frac{1}{\sqrt{(\omega_0/\omega)^2 + 1}}$$

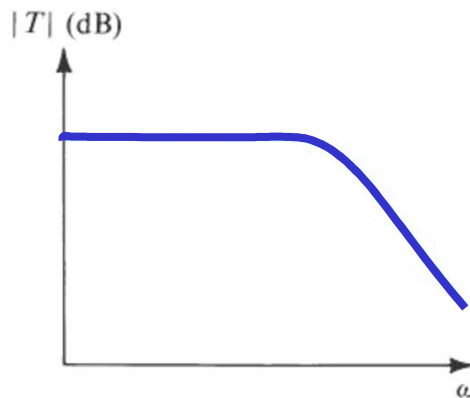
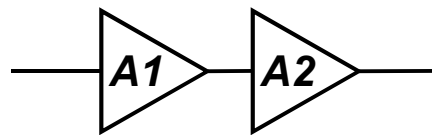
$$\angle T(\omega) = \tan^{-1}(\omega_0/\omega)$$



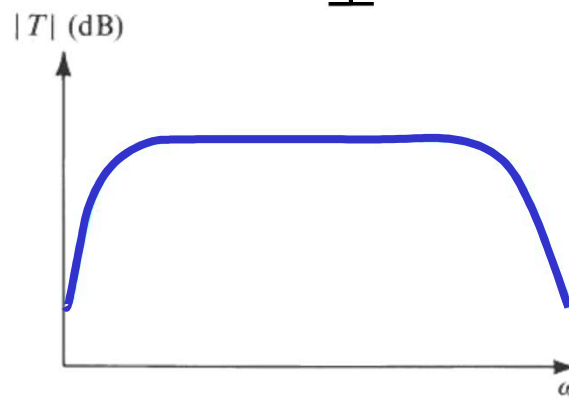
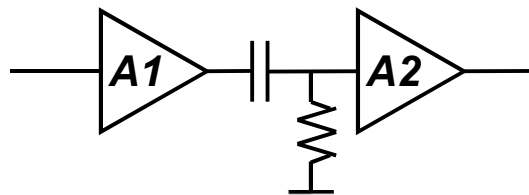


Amplifier Classifications

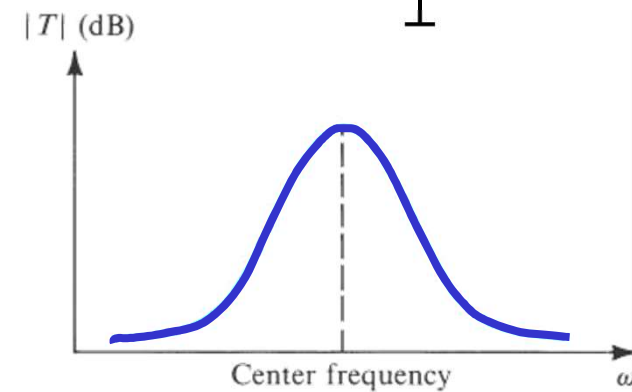
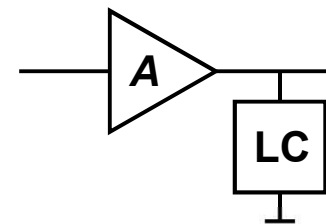
Direct coupled amplifier



**Capacitively coupled amplifier
(ac coupled)**



**Tuned amplifier
(bandpass)**





Problem Solving and Analysis

- Understand the problem
 - **Learn to ask questions**
 - **“Asking the right question is half the answer”**
- Divide the problem into modules
- Represent each module with equivalent model
- Plug in the models to simplify the problem
- Solve the problem with **reasonable approximation**
 - **Gain insight**



武林高手

- 劍招 vs. 劍意
- 張三豐 傳授 張無忌 太極劍
- 風清揚 傳授 令狐沖 獨孤九劍
- 劍招: equation, calculation \Rightarrow practice
- 劍意: intuition, insight \Rightarrow “feel” and “see” how circuits work